Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 80 A

80PF(R)... 80PF(R)...W

DO-203AB (DO-5) DO-203AB (DO-5)

FEATURES

- High surge current capability
- Designed for a wide range of applications
- Stud cathode and stud anode version
- Wire version available
- Low thermal resistance
- Designed and qualified for multiple level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT

TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

PRODUCT SUMMARY	
$I_{F(AV)}$	80 A
Package	DO-203AB (DO-5)
Circuit configuration	Single diode

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		80	A
	T_C	123	°C
$I_{F(RMS)}$		126	A
I_{FSM}	50 Hz	1200	A
	60 Hz	1250	
I^2t	50 Hz	7100	A^2s
	60 Hz	6450	
V_{RRM}	Range	1400 to 1600	V
T_J		-55 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM}, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT T_J = 150 °C mA
VS-80PF(R)...(W)	140	1400	1650	4.5
	160	1600	1900	

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave			80	A
					123	°C
Maximum RMS forward current	$I_{F(RMS)}$				126	A
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T_J = 150 °C	1200	A
		t = 8.3 ms			1250	
		t = 10 ms	100 % V_{RRM} reapplied		1000	
		t = 8.3 ms			1050	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied		7100	A^2s
		t = 8.3 ms			6450	
		t = 10 ms	100 % V_{RRM} reapplied		5000	
		t = 8.3 ms			4550	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied			71 000	$A^2\sqrt{s}$
Low level value of threshold voltage	$V_{F(TO)}$	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T_J = T_J maximum			0.73	V
Low level value of forward slope resistance	r_f	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T_J = T_J maximum			3.0	mΩ
Maximum forward voltage drop	V_{FM}	I_{pk} = 220 A, T_J = 25 °C, t_p = 400 µs rectangular wave			1.46	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T_J, T_{Stg}		-55 to 180	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.30	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased	0.25	
Allowable mounting torque		Not lubricated threads, tighting on nut (1)	3.4 (30)	N · m (lbf · in)
		Lubricated threads, tighting on nut (1)	2.3 (20)	
		Not lubricated threads, tighting on Hexagon (2)	4.2 (37)	
		Lubricated threads, tighting on Hexagon (2)	3.2 (28)	
Approximate weight			15.8	g
			0.56	oz.
Case style		See dimensions - link at the end of datasheet	DO-203AB (DO-5)	

Notes

(1) Recommended for pass-through holes

(2) Torque must be applicable only to Hexagon and not to plastic structure, recommended for holed heatsink

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.14	0.10	T_J = T_J maximum	K/W
120°	0.16	0.17		
90°	0.21	0.22		
60°	0.30	0.31		
30°	0.50	0.50		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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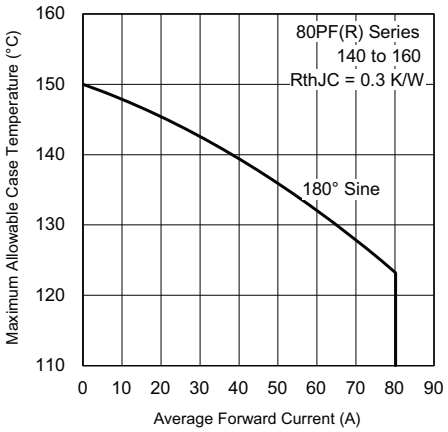

Fig. 1 - Current Ratings Characteristics

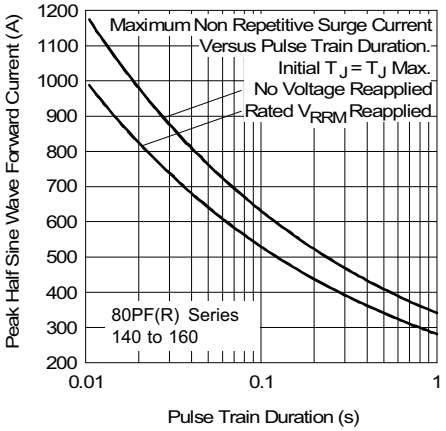

Fig. 3 - Forward Power Loss Characteristics

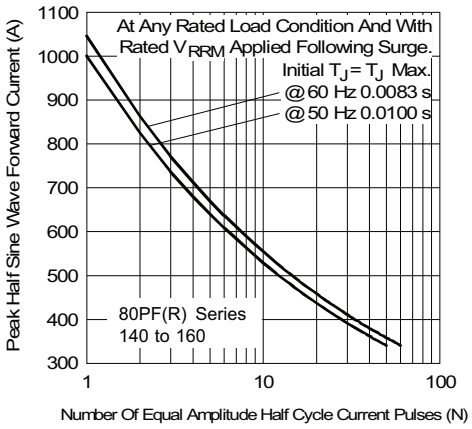

Fig. 2 - Current Ratings Characteristics

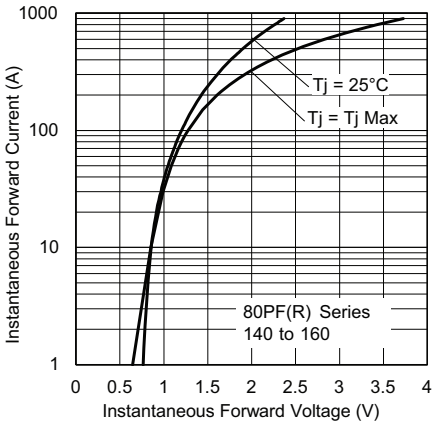

Fig. 4 - Forward Power Loss Characteristics

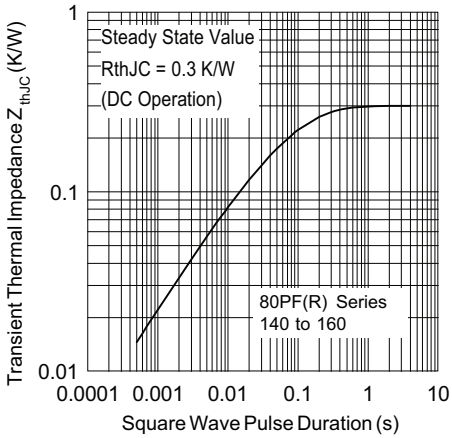

Fig. 5 - Maximum Non-Repetitive Surge Current

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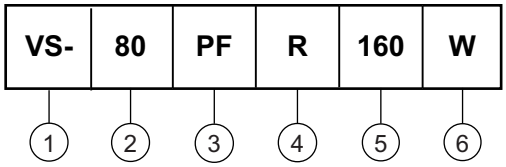
ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - 80 = Standard device

3 - PF = Plastic package

4 - • None = Stud normal polarity (cathode to stud)
• R = Stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

6 - • None = Standard terminal
(see dimensions for 80PF(R)... - link at the end of datasheet)
• W = Wire terminal
(see dimensions for 80PF(R)...W - link at the end of datasheet)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95345

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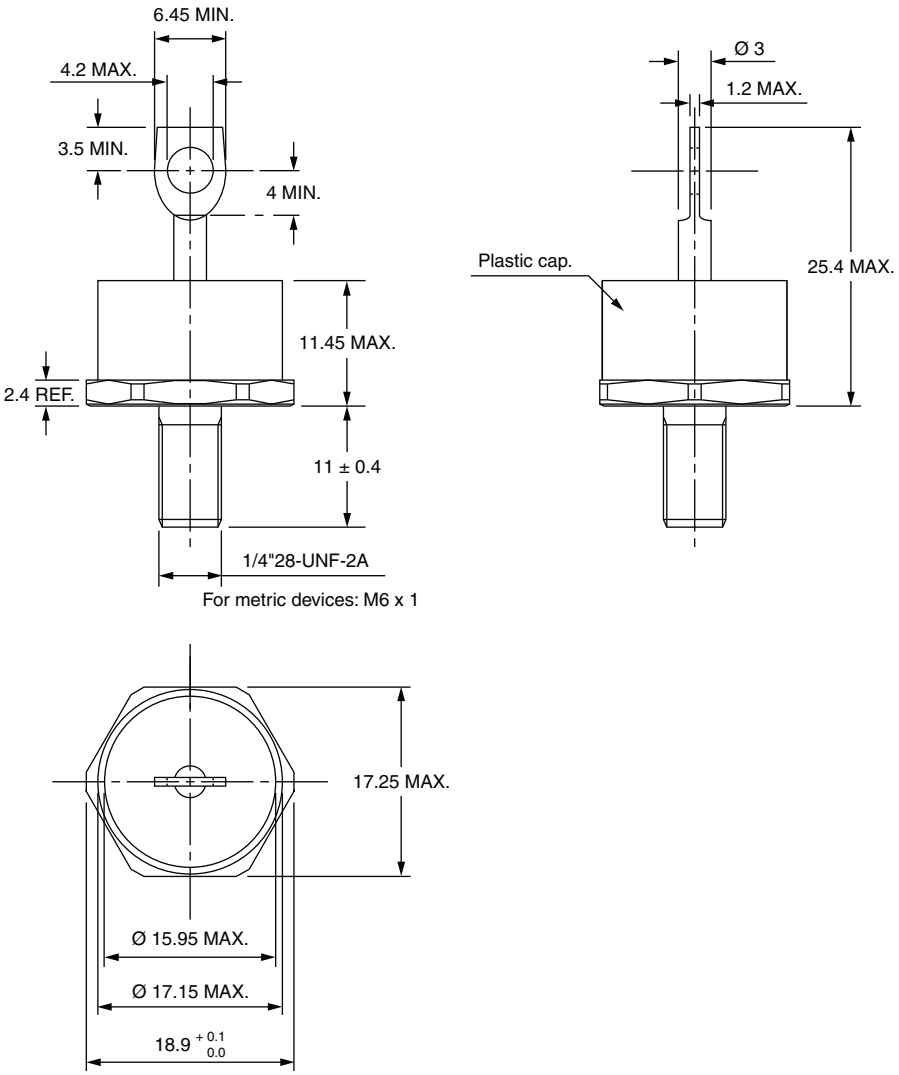
DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R) AND 95PF(R) SERIES in millimeters



Note

- For metric device please contact factory

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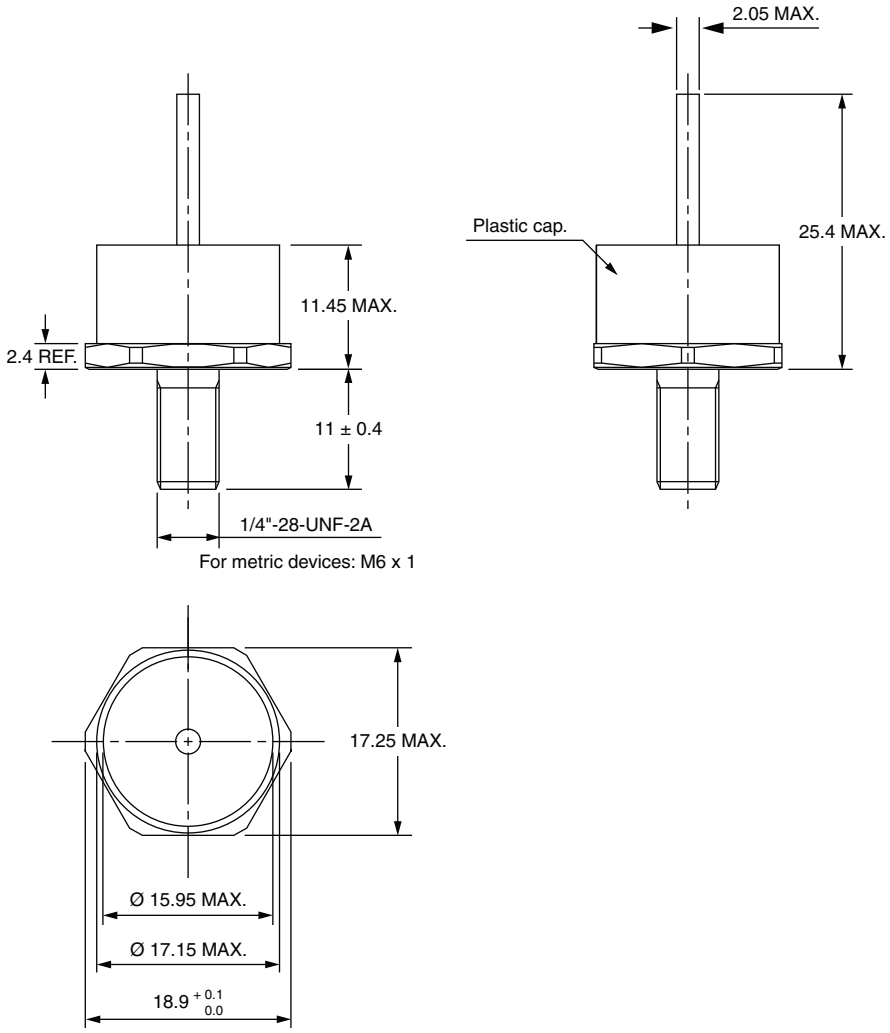
DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W) AND 95PF(R)...(W) SERIES in millimeters



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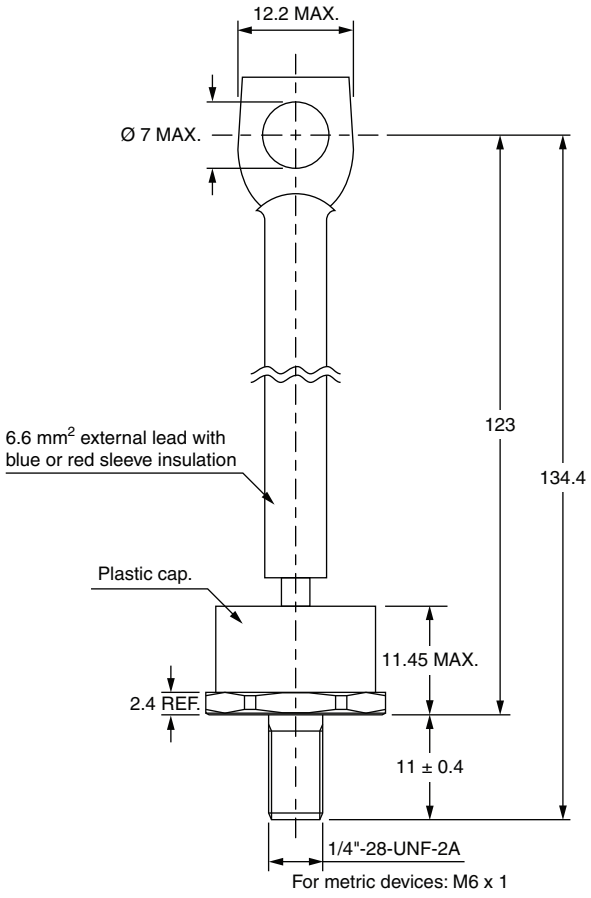
DIMENSIONS FOR 52PF(R), 82PF(R) AND 97PF(R) SERIES in millimeters



Note

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:
moschip.ru
moschip.ru_4
moschip.ru_6
moschip.ru_9